



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

2SC6095 — NPN Epitaxial Planar Silicon Transistor

High-Voltage Switching Applications

Applications

- DC / DC converter, relay drivers, lamp drivers, motor drivers, inverter.

Features

- Adoption of FBET, MBIT process.
- High current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.
- High allowable power dissipation.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		120	V
Collector-to-Emitter Voltage	V _{CES}		120	V
Collector-to-Emitter Voltage	V _{CEO}		80	V
Emitter-to-Base Voltage	V _{EBO}		6.5	V
Collector Current	I _C		2.5	A
Collector Current (Pulse)	I _{CP}		4	A
Base Current	I _B		500	mA
Collector Dissipation	P _C	Mounted on a ceramic board (250mm ² ×0.8mm)	1.3	W
		T _C =25°C	3.5	W
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I _{CB0}	V _{CB} =70V, I _E =0A			1	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} =4V, I _C =0A			1	μA
DC Current Gain	h _{FE}	V _{CE} =5V, I _C =100mA	300		600	

Marking : QF

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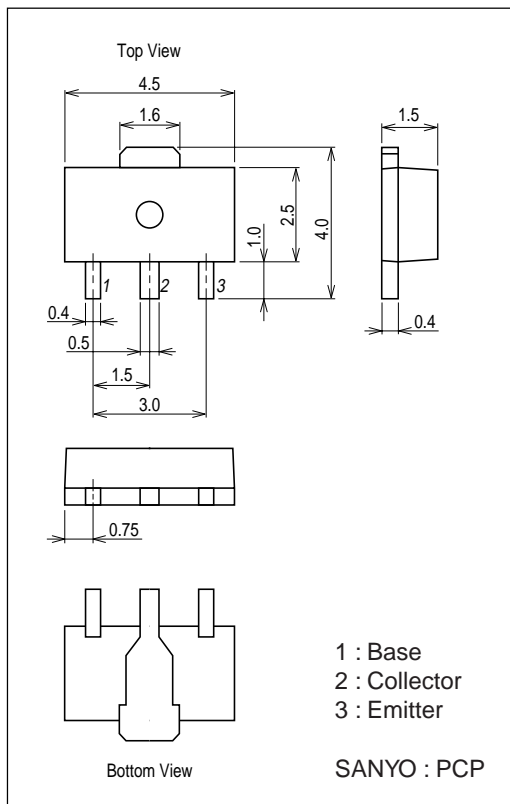
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Gain-Bandwidth Product	f_T	$V_{CE}=10V, I_C=500mA$		350		MHz
Output Capacitance	C_{ob}	$V_{CB}=10V, f=1MHz$		14		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)1}$	$I_C=1A, I_B=50mA$		100	150	mV
	$V_{CE(sat)2}$	$I_C=1A, I_B=100mA$		90	135	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=1A, I_B=100mA$		0.9	1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu A, I_E=0A$	120			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CES}$	$I_C=100\mu A, R_{BE}=0\Omega$	120			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1mA, R_{BE}=\infty$	80			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu A, I_C=0A$	6.5			V
Turn-ON Time	t_{on}	See specified Test Circuit.		40		ns
Storage Time	t_{stg}	See specified Test Circuit.		920		ns
Fall Time	t_f	See specified Test Circuit.		32		ns

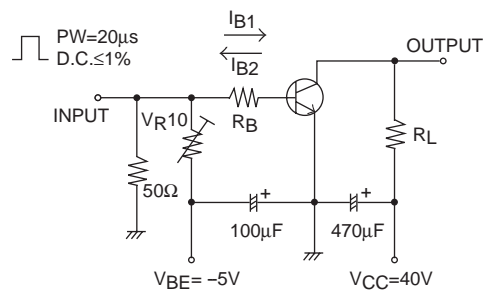
Package Dimensions

unit : mm

7007A-004

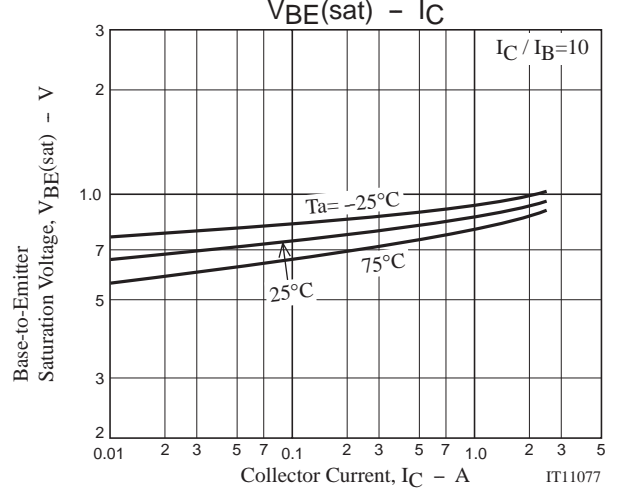
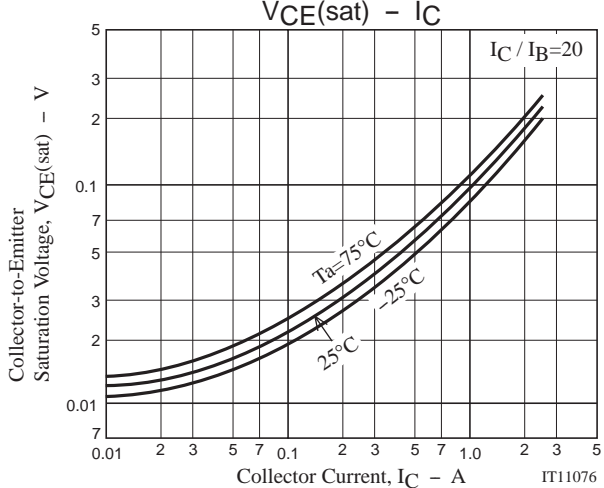
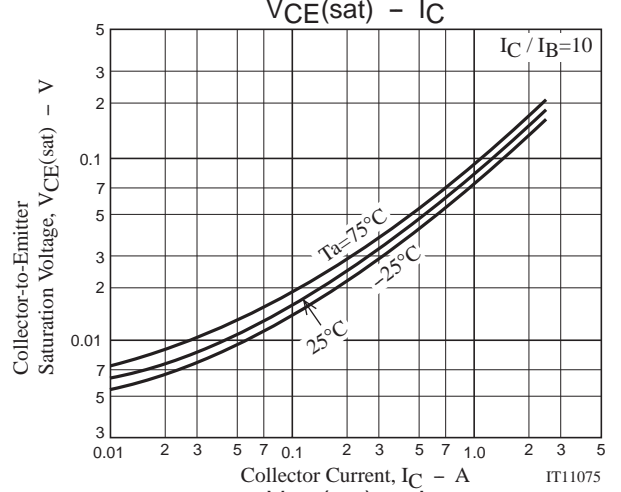
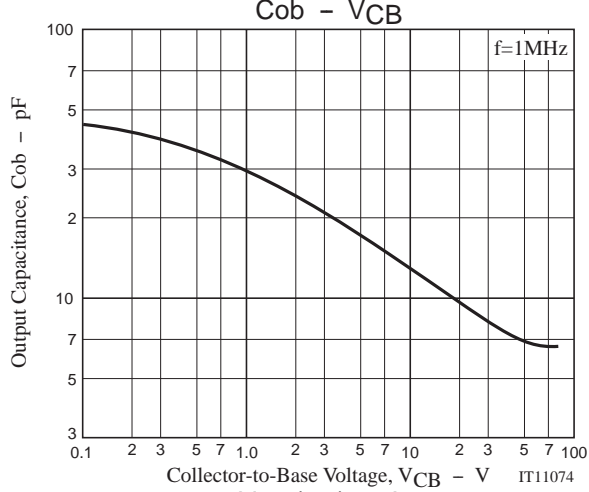
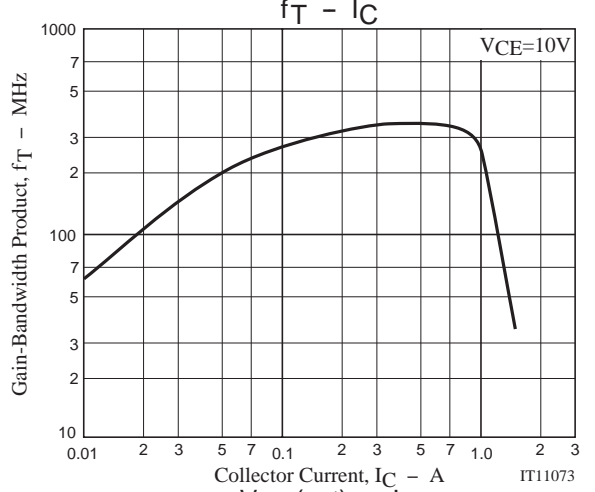
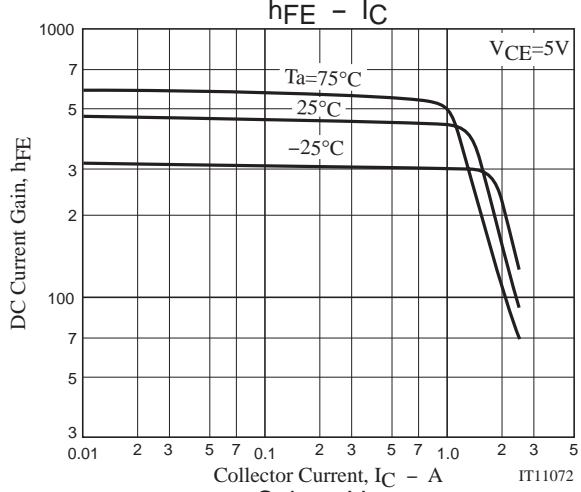
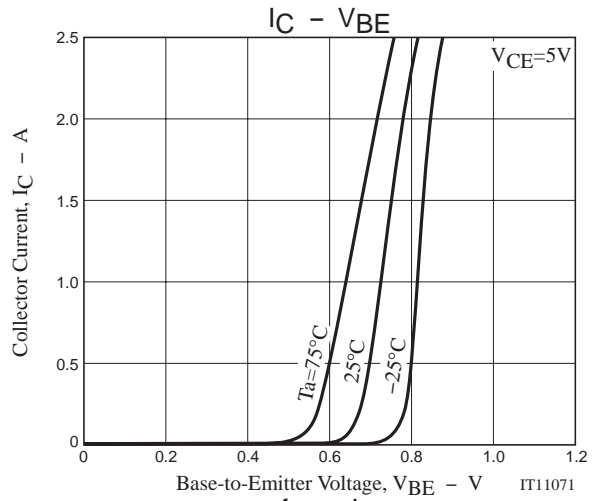
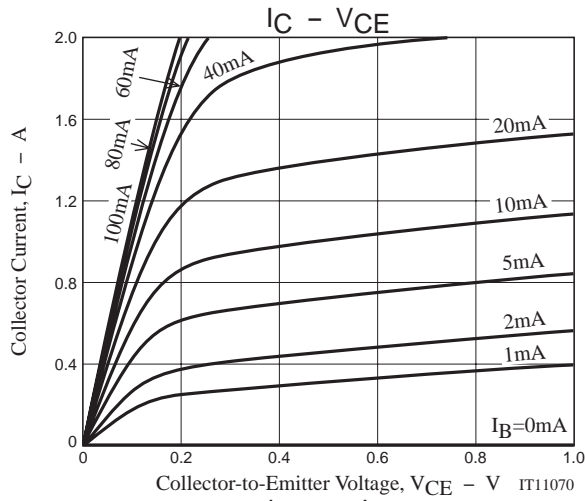


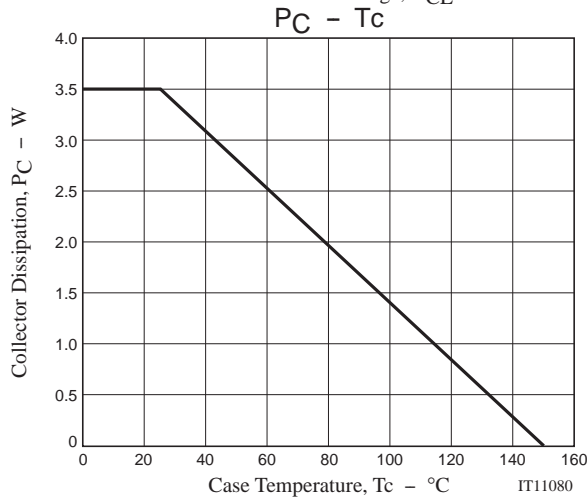
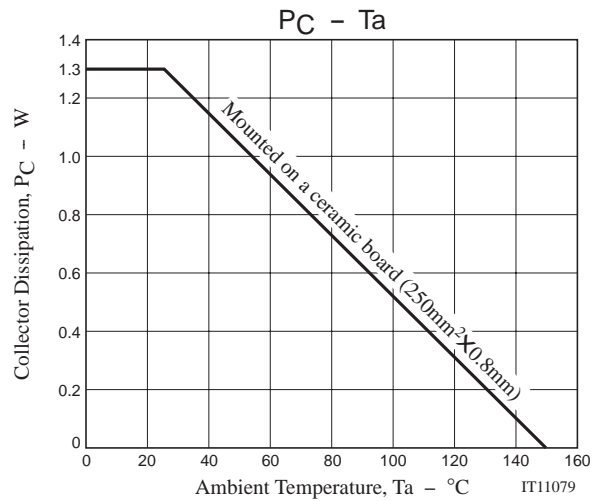
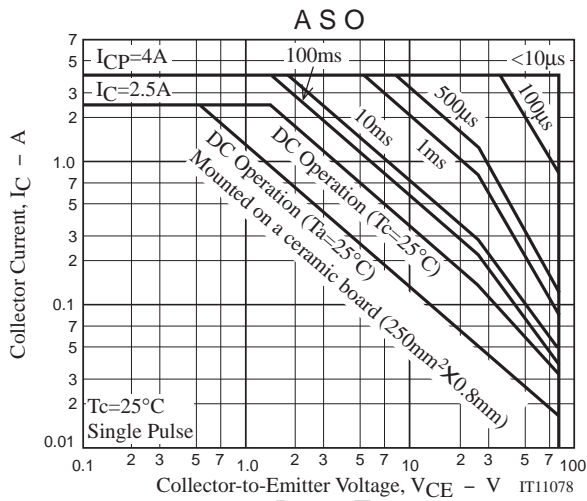
Switching Time Test Circuit



$$10I_{B1} = -10I_{B2} = I_C = 0.5A$$

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- Подбор аналогов;
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